Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-179-3475

Inclosure Material:	
Glass	
Overall Length:	
0.300 inches	
Terminal Length:	
1.000 inches	
Overall Diameter:	
0.107 inches	
Function For Which Designed:	
Voltage reference	
Mounting Method:	
Terminal	
Features Provided:	
Hermetically sealed case and quality assurance level txv	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
6.7 regulator voltage	
Voltage Tolerance In Percent:	
-5.0/+5.0	
Current Rating Per Characteristic:	
60.00 milliamperes repetitive peak forward current	
Power Rating Per Characteristic:	
400.0 milliwatts small-signal input power, common-collector preset	
Maximum Operating Tempurature Per Measurement Point:	
175.0 degrees celsius ambient air	
Test Data Document:	
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in sp	cification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on cer	tain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).	
Terminal Type And Quantity:	
2 uninsulated wire lead	
Specification Data:	
81349-mil-s-19500/452 government specification	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	